

THIS SPEC IS OBSOLETE

- Spec No: 38-03027
- Spec Title: PALCE22V10 FLASH-ERASABLE REPROGRAMMABLE CMOS PAL(R) DEVICE
- Sunset Owner: Adrian Mendes (AMV)
- Replaced by: None



PALCE22V10 is a replacement device for PALC22V10, PALC22V10B, and PALC22V10D. USE ULTRA37000TM FOR

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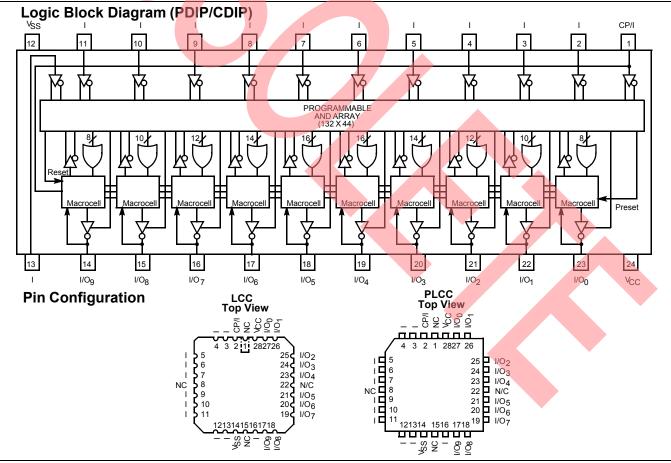
PALCE22V10

Flash-erasable Reprogrammable CMOS PAL[®] Device

Features

- · Low power
 - 90 mA max. commercial (10 ns)
 - 130 mA max. commercial (5 ns)
- CMOS Flash EPROM technology for electrical erasability and reprogrammability
- Variable product terms
 - 2 × (8 through 16) product terms
- User-programmable macrocell
- Output polarity control
- Individually selectable for registered or combinatorial operation
- Up to 22 input terms and 10 outputs

- DIP, LCC, and PLCC available
 - 5 ns commercial version
 - 4 ns t_{CO}
 - 3 ns t_S 5 ns t_{PD}
 - 181-MHz state machine
 - 10 ns military and industrial versions
 - 7 ns t_{CO}
 - 6 ns t_S
 - 10 ns t_{PD}
 - 110-MHz state machine
 - 15-ns commercial, industrial, and military versions
 - 25-ns commercial, industrial, and military versions
- High reliability
 - Proven Flash EPROM technology
 - 100% programming and functional testing



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Selection Guide

Generic Part Number	t _{PD} ns		t _S	ns	t _{co}	ns	I _{CC} mA		
	Com'l	Mil/Ind	Com'l	Mil/Ind	Com'l	Mil/Ind	Com'l	Mil/Ind	
PALCE22V10-5	5		3		4		130		
PALCE22V10-7	7.5		5		5		130		
PALCE22V10-10	10	10	6	6	7	7	90	150	
PALCE22V10-15	15	15	10	10	8	8	90	120	
PALCE22V10-25	25	25	15	15	15	15	90	120	

Functional Description

The Cypress PALCE22V10 is a CMOS Flash-erasable second-generation programmable array logic device. It is implemented with the familiar sum-of-products (AND-OR) logic structure and the programmable macrocell.

The PALCE22V10 is executed in a 24-pin 300-mil molded DIP, a 300-mil cerDIP, a 28-lead square ceramic leadless chip carrier, a 28-lead square plastic leaded chip carrier, and provides up to 22 inputs and 10 outputs. The PALCE22V10 can be electrically erased and reprogrammed. The programmable macrocell provides the capability of defining the architecture of each output individually. Each of the ten potential outputs may be specified as "registered" or "combinatorial." Polarity of each output may also be individually selected, allowing complete flexibility of output configuration. Further configurability is provided through "array" configurable "output enable" for each potential output. This feature allows the 10 outputs to be reconfigured as inputs on an individual basis, or alternately used as a combination I/O controlled by the programmable array.

PALCE22V10 features a variable product term architecture. There are 5 pairs of product term sums beginning at 8 product terms per output and incrementing by 2 to 16 product terms per output. By providing this variable structure, the PALCE22V10 is optimized to the configurations found in a majority of applications without creating devices that burden the product term structures with unusable product terms and lower performance.

Additional features of the Cypress PALCE22V10 include a synchronous preset and an asynchronous reset product term. These product terms are common to all macrocells, eliminating the need to dedicate standard product terms for initialization functions. The device automatically resets upon power-up.

The PALCE22V10, featuring programmable macrocells and variable product terms, provides a device with the flexibility to

implement logic functions in the 500- to 800-gate-array complexity. Since each of the ten output pins may be individually configured as inputs on a temporary or permanent basis, functions requiring up to 21 inputs and only a single output and down to twelve inputs and ten outputs are possible. The ten potential outputs are enabled using product terms. Any output pin may be permanently selected as an output or arbitrarily enabled as an output and an input through the selective use of individual product terms associated with each output. Each of these outputs is achieved through an individual programmable macrocell. These macrocells are programmable to provide a combinatorial or registered inverting or non-inverting output. In a registered mode of operation, the output of the register is fed back into the array, providing current status information to the array. This information is available for establishing the next result in applications such as control state machines. In a combinatorial configuration, the combinatorial output or, if the output is disabled, the signal present on the I/O pin is made available to the array. The flexibility provided by both programmable product term control of the outputs and variable product terms allows a significant gain in functional density through the use of programmable logic.

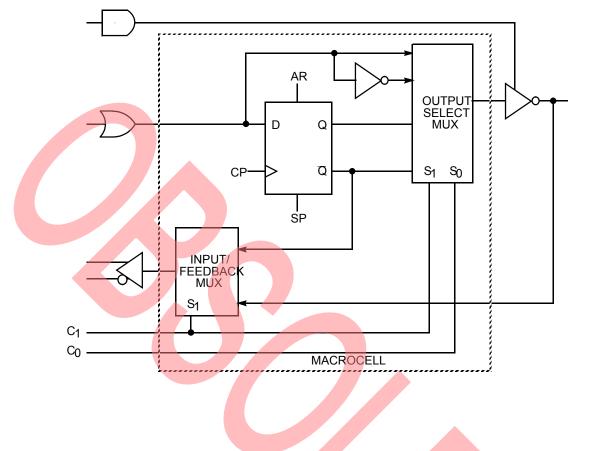
Along with this increase in functional density, the Cypress PALCE22V10 provides lower-power operation through the use of CMOS technology, and increased testability with Flash reprogrammability.

Configuration Table

	Registered/Combinatorial										
C ₁	C ₀	Configuration									
0	0	Registered/Active LOW									
0	1	Registered/Active HIGH									
1	0	Combinatorial/Active LOW									
1	1	Combinatorial/Active HIGH									

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Macrocell





PALCE22V10

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	–65°C to +150°C
Ambient Temperature with Power Applied	–55°C to +125°C
Supply Voltage to Ground Po (Pin 24 to Pin 12)	ntential
DC Voltage Applied to Output in High-Z State	ts
DC Input Voltage	

Electrical Characteristics Over the Operating Range^[2]

Output Current into Outputs (LOW)	16 mA
DC Programming Voltage	12.5V
Latch-up Current	> 200 mA
Static Discharge Voltage (per MIL-STD-883, Method 3015)	.>2001V
Operating Range	

Range	Ambient Temperature	v _{cc}
Commercial	0°C to +75°C	5V ±5%
Industrial	–40°C to +85°C	5V ±10%
Military ^[1]	–55°C to +125°C	5V ±10%

Parameter	Description	Test Condi	tions		Min.	Max.	Unit		
V _{OH}	Output HIGH Voltage	V _{CC} = Min.,	I _{OH} = -3.2 mA	Com'l	2.4		V		
		$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = –2 mA	Mil/Ind					
V _{OL}	Output LOW Voltage	V _{CC} = Min.,	I _{OL} = 16 mA	Com'l		0.5	V		
		$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 12 mA	Mil/Ind					
V _{IH}	Input HIGH Level	Guaranteed Input Logical HIGH Vo	Itage for All Inputs ^[3]		2.0		V		
V _{IL} ^[4]	Input LOW Level	Guaranteed Input Logical LOW Vol	-0.5	0.8	V				
I _{IX}	Input Leakage Current	$V_{SS} \le V_{IN} \le V_{CC}, V_{CC} = Max.$	-10	10	μA				
I _{OZ}	Output Leakage Current	V _{CC} = Max., V _{SS} ≤ V _{OUT} ≤ V _{CC}	V _{CC} = Max., V _{SS} ≤ V _{OUT} ≤ V _{CC}						
I _{SC}	Output Short Circuit Current	V _{CC} = Max., V _{OUT} = 0.5V ^[5,6]			-30	-130	mA		
I _{CC1}	Standby Power Supply	$V_{CC} = Max.,$	10, 15, 25 ns	Com'l		90	mA		
	Current	V _{IN} = GND, Outputs Open in Unprogrammed	5, 7.5 ns			130	mA		
		Device	15, 25 ns	Mil/Ind		120	mA		
			10 ns			120	mA		
I _{CC2} ^[6]	Operating Power Supply	$V_{CC} = Max., V_{IL} = 0V, V_{IH} = 3V,$	10, 15, 25 ns	Com'l		110	mA		
	Current	Output Open, Device Programmed as a 10-bit Counter,	5, 7.5 ns	Com'l		140	mA		
		f = 25 MHz	15, 25 ns	Mil/Ind		130	mA		
			10 ns	Mil/Ind		130	mA		

Capacitance^[6]

Parameter	Description	Test Conditions	Min.	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 2.0V @ f = 1 MHz		10	pF
C _{OUT}	Output Capacitance	V _{OUT} = 2.0V @ f = 1 MHz		10	pF

Endurance Characteristics^[6]

Parameter	Description	Test Conditions	I	Min.	Max.	Unit
Ν	Minimum Reprogramming Cycles	Normal Programming Conditions	·	100		Cycles

Notes:

T_A is the "instant on" case temperature.
See the last page of this specification for Group A subgroup testing information.

These are absolute values with respect to device ground. All overshoots due to system or tester noise are included.
V_{IL} (Min.) is equal to -3.0V for pulse durations less than 20 ns.

5. Not more than one output should be tested at a time. Duration of the short circuit should not be more than one second. V_{OUT} = 0.5V has been chosen to avoid test problems caused by tester ground degradation.6. Tested initially and after any design or process changes that may affect these parameters.



AC Test Loads and Waveforms R1238Ω R1238Ω (319Ω MIL) (319Ω MIL) 5VO 5V O-~~ ^ ^ . OUTPUTO OUTPUTO OUTPUTO 750Ω R2170Ω R2170Ω Ş (1.2KΩ 5 pF Cı Cı (236Ω MIL) (236Ω MIL) ÌMIL) INCLUDING INCLUDING JIG AND JIG AND SCOPE SCOPE (a) (b) (C) ALL INPUT PULSES 3.0V 90% 90% 10% 10% GND < 2 ns < 2 ns (d) Equivalent to: THÉVENIN Equivalent (Commercial) Equivalent to: THÉVENIN Equivalent (Military) 99Ω **136**Ω OUTPUT O O 2.08V = V_{THC} -O 2.13V = V_{THM} \sim OUTPUTO ~~~ Load Speed C Package 5, 7.5, 10, 15, 25 ns 50 pF PDIP, CDIP, PLCC, LCC Parameter Vx **Output Waveform Measurement Level** 1.5V t_{ER (-)} Von-0.5V VX 2.6V t_{ER (+)} 0.5V Vx V_{OL} 0V 1.5V_ t_{EA (+)} VOH Vx V_{thc} t_{EA (-)} ٧x 0.5V VOL (e) Test Waveforms

Commercial Switching Characteristics PALCE22V10 [2,7]

		22V10-5		22V10-7		22V10-10		22V10-15		22V10-25		
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
t _{PD}	Input to Output Propagation Delay ^[8]	3	5	3	7.5	3	10	3	15	3	25	ns
t _{EA}	Input to Output Enable Delay ^[9]		6		8		10		15		25	ns
t _{ER}	Input to Output Disable Delay ^[10]		6		8		10		15		25	ns
t _{CO}	Clock to Output Delay ^[8]	2	4	2	5	2	7	2	8	2	15	ns

Notes:

7. Part (a) of AC Test Loads and Waveforms is used for all parameters except teR and teA(+). Part (b) of AC Test Loads and Waveforms is used for teR. Part (c) of AC Test Loads and Waveforms is used for t_{EA(+)}. 8. Min. times are tested initially and after any design or process changes that may affect these parameters.

The test load of (a) of AC Test Loads and Waveforms is used for measuring $t_{EA(-)}$. The test load of (c) of AC Test Loads and Waveforms is used for measuring $t_{EA(-)}$ only. Please see (e) of AC Test Loads and Waveforms for enable and disable test waveforms and measurement reference levels. 9.

10. This parameter is measured as the time after output disable input that the previous output data state remains stable on the output. This delay is measured to the point at which a previous HIGH level has fallen to 0.5V below V_{OH} min. or a previous LOW level has risen to 0.5V above V_{OL} max. Please see (e) of AC Test Loads and Waveforms for enable and disable test waveforms and measurement reference levels.



Commercial Switching Characteristics PALCE22V10 (continued)^[2, 7]

		22V	10-5	22V	10-7	22V′	10-10	22V1	10-15	22V1	0-25	
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
t _{S1}	Input or Feedback Set-Up Time	3		5		6		10		15		ns
t _{S2}	Synchronous Preset Set-Up Time	4		6		7		10		15		ns
t _H	Input Hold Time	0		0		0		0		0		ns
t _P	External Clock Period (t _{CO} + t _S)	7		10		12		20		30		ns
t _{WH}	Clock Width HIGH ^[6]	2.5		3		3		6		13		ns
t _{WL}	Clock Width LOW ^[6]	2.5		3		3		6		13		ns
f _{MAX1}	External Maximum Frequency (1/(t _{CO} + t _S)) ^[11]	143		100		76.9		55.5		33.3		MHz
f _{MAX2}	Data Path Maximum Frequency (1/(t _{WH} + t _{WL})) ^[6, 12]	200		166		142		83.3		35.7		MHz
f _{MAX3}	Internal Feedback Maximum Frequency (1/(t _{CF} + t _S)) ^[6,13]	181		133		111		68.9		38.5		MHz
t _{CF}	Register Clock to Feedback Input ^[6,14]		2.5		2.5		3		4.5		13	ns
t _{AW}	Asynchronous Reset Width	8		8		10		15		25		ns
t _{AR}	Asynchronous Reset Recovery Time	4		5		6		10		25		ns
t _{AP}	Asynchronous Reset to Registered Output Delay		7.5		12		13		20		25	ns
t _{SPR}	Synchronous Preset Recovery Time	4		6		8		10		15		ns
t _{PR}	Power-up Reset Time ^[6,15]	1		1		1		1		1		μS

Military and Industrial Switching Characteristics PALCE22V10 [2,7]

		22V	10-10	22V	10-15	22V10-25		
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Unit
t _{PD}	Input to Output Propagation Delay ^[8]	3	10	3	15	3	25	ns
t _{EA}	Input to Output Enable Delay ^[9]		10		15		25	ns
t _{ER}	Input to Output Disable Delay ^[10]		10		15		25	ns
t _{CO}	Clock to Output Delay ^[8]	2	7	2	8	2	15	ns
t _{S1}	Input or Feedback Set-up Time	6		10		18		ns
t _{S2}	Synchronous Preset Set-up Time	7		10		18		ns
t _H	Input Hold Time	0		0		0		ns
t _P	External Clock Period $(t_{CO} + t_S)$	12		20		33		ns
t _{WH}	Clock Width HIGH ^[6]	3		6		14		ns
t _{WL}	Clock Width LOW ^[6]	3		6		14		ns
f _{MAX1}	External Maximum Frequency $(1/(t_{CO} + t_S))^{[11]}$	76.9		50.0		30.3		MHz
f _{MAX2}	Data Path Maximum Frequency $(1/(t_{WH} + t_{WL}))^{[6, 12]}$	142		83.3		35.7		MHz

Notes:

11. This specification indicates the guaranteed maximum frequency at which a state machine configuration with external feedback can operate.

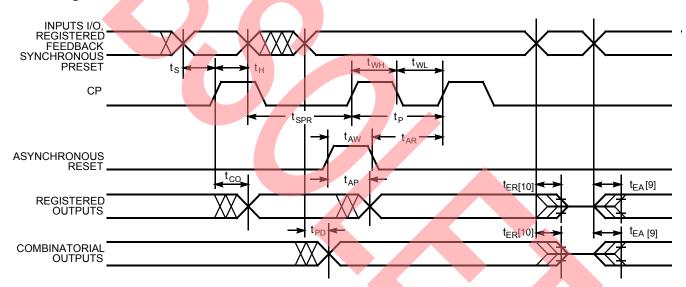
11. Ihis specification indicates the guaranteed maximum frequency at which a state machine configuration with external feedback can operate.
12. This specification indicates the guaranteed maximum frequency at which the device can operate in data path mode.
13. This specification indicates the guaranteed maximum frequency at which a state machine configuration with internal only feedback can operate.
14. This parameter is calculated from the clock period at f_{MAX} internal (1/f_{MAX3}) as measured (see Note above) minus t_S.
15. The registers in the PALCE22V10 have been designed with the capability to reset during system power-up. Following power-up, all registers will be reset to a logic LOW state. The output state will depend on the polarity of the output buffer. This feature is useful in establishing state machine initialization. To insure proper operation, the rise in V_{CC} must be monotonic and the timing constraints depicted in Power-Up Reset Waveform must be satisfied.



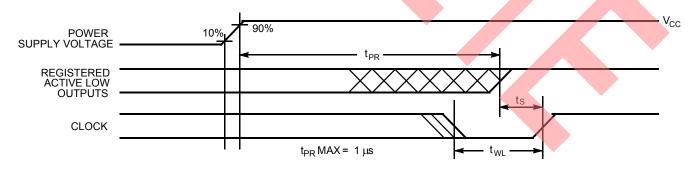
Military and Industrial Switching Characteristics PALCE22V10 (continued)^[2, 7]

		22V	10-10	22V10-15		22V10-25		
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Unit
f _{MAX3}	Internal Feedback Maximum Frequency (1/(t _{CF} + t _S)) ^[6, 13]	111		68.9		32.2		MHz
t _{CF}	Register Clock to Feedback Input ^[6, 14]		3		4.5		13	ns
t _{AW}	Asynchronous Reset Width	10		15		25		ns
t _{AR}	Asynchronous Reset Recover <mark>y Ti</mark> me	6		12		25		ns
t _{AP}	Asynchr <mark>ono</mark> us Reset to Registered Output Delay		12		20		25	ns
t _{SPR}	Synchronous Preset Recovery Time	8		20		25		ns
t _{PR}	Power-up Reset Time ^[6, 15]	1		1		1		μS

Switching Waveforms

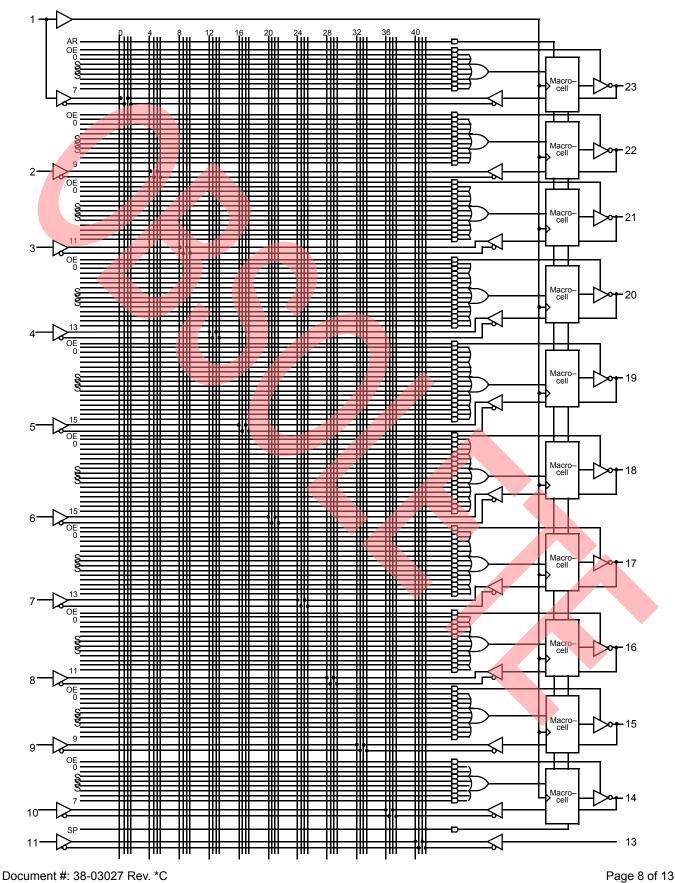


Power-Up Reset Waveform^[15]





Functional Logic Diagram for PALCE22V10



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Ordering Information

I _{CC} (mA)	t _{PD} (ns)	t _S (ns)	t _{CO} (ns)	Ordering Code	Package Name	Package Type	Operating Range
130	5	3	4	PALCE22V10-5PC	P13	24-lead (300 MIL) Molded DIP	Commercial
				PALCE22V10-5JC	J64	28-lead Plastic Leaded Chip Carrier	
130	7.5	5	5	PALCE22V10-7JC	J64	28-lead Plastic Leaded Chip Carrier	Commercial
				PALCE22V10-7PC	P13	24-lead (300-Mil) Molded DIP	
90	10	6	7	PALCE22V10-10JC	J64	28-lead Plastic Leaded Chip Carrier	Commercial
				PALCE22V10-10PC	P13	24-lead (300-Mil) Molded DIP	
150	10	6	7	PALCE22V10-10JI	J64	28-lead Plastic Leaded Chip Carrier	Industrial
				PALCE22V10-10PI	P13	24-lead (300-Mil) Molded DIP	
				PALCE22V10-10LMB 5962-89841063X	L64	28-Square Leadless Chip Carrier	Military
				PALCE22V10-10KMB 5962-8984106KX	K73	24-lead Rectangular Cerpack	
				PALCE22V10-10DMB 5962-8984106LX	D14	24-lead (300 MIL) CerDIP	
90	15	10	8	PALCE22V10-15JC	J64	28-lead Plastic Leaded Chip Carrier	Commercial
				PALCE22V10-15PC	P13	24-lead (300-Mil) Molded DIP	
120	15	10	8	PALCE22V10-15KMB 59 <mark>62-8</mark> 984102KX	K73	24-lead Rectangular Cerpack	Military
				PALCE22V10-15KMB 5962-8984103KX	K73	24-lead Rectangular Cerpack	
				PALCE22V10-15KMB 5962-8984105KX	K73	24-lead Rectangular Cerpack	
				PALCE22V10-15DMB 5962-8984102LX	D14	24-lead (300 MIL) CerDIP	
				PALCE22V10-15DMB 5962-8984103LX	D14	24-lead (300 MIL) CerDIP	
				PALCE22V10-15LMB 5962-89841033X	L64	28-Square Leadless Chip Carrier	
				PALCE22V10-15LMB 5962-89841053X	L64	28-Square Leadless Chip Carrier]
90	25	15	15	PALCE22V10-25JC	J64	28-lead Plastic Leaded Chip Carrier	Commercial
				PALCE22V10-25PC	P13	24-lead (300-Mil) Molded DIP	
120	25	15	15	PALCE22V10-25LMB 5962-89841043X	L64	28-square Leadless Chip Carrier	Military

MILITARY SPECIFICATIONS Group A Subgroup Testing

DC Characteristics

Parameter	Subgroups
V _{OH}	1, 2, 3
V _{OL}	1, 2, 3
V _{IH}	1, 2, 3
V _{IL}	1, 2, 3
I _{IX}	1, 2, 3
I _{OZ}	1, 2, 3

DC Characteristics

Parameter	Subgroups
I _{CC}	1, 2, 3

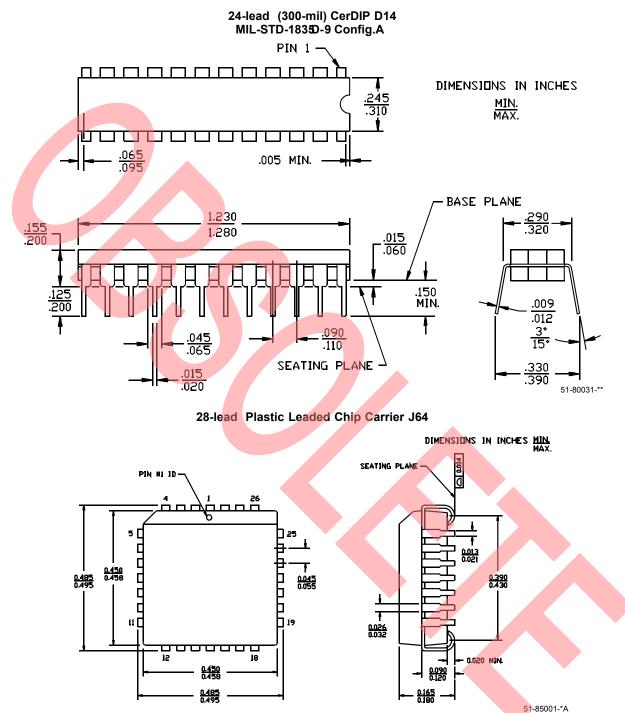
Switching Characteristics

Parameter	Subgroups
t _{PD}	9, 10, 11
t _{CO}	9, 10, 11
t _S	9, 10, 11
t _H	9, 10, 11



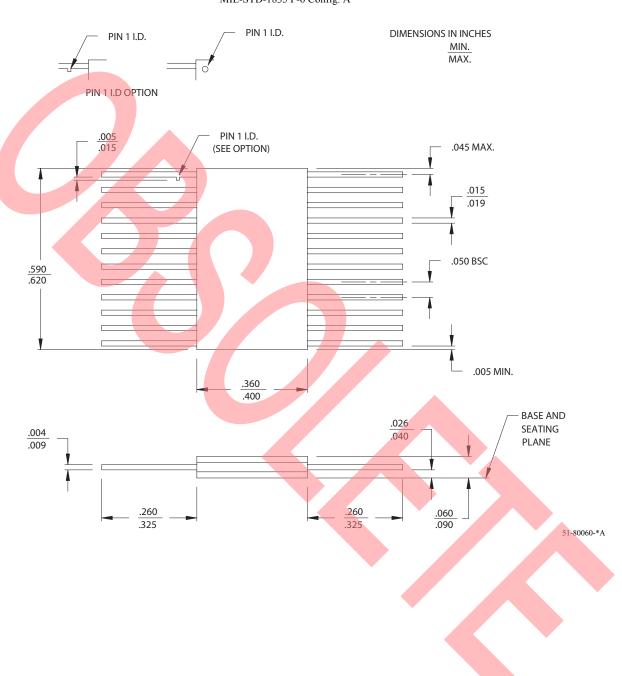
PALCE22V10

Package Diagrams





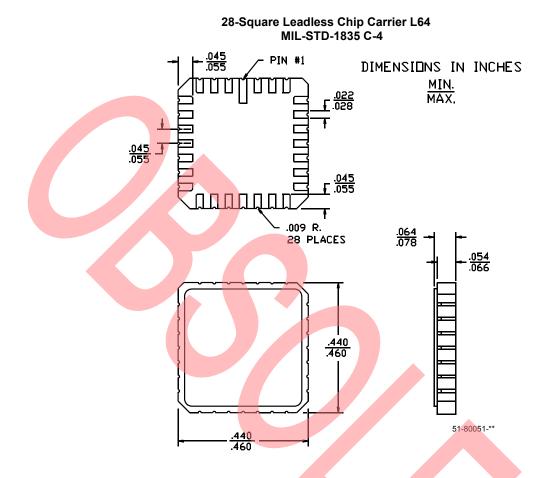
Package Diagrams (continued)



24-Lead Rectangular Cerpack K73 MIL-STD-1835 F-6 Config. A



Package Diagrams (continued)



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Page 12 of 13

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Document History Page

Document Title: PALCE22V10 Flash-erasable Reprogrammable CMOS PAL [®] Device Document Number: 38-03027					
REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change	
**	106372	07/11/01	SZV	Change from Spec Number: 38-00447 to 38-03027	
*A	114640	06/25/02	OOR	Added a note on the title page referring all new designs to this device Added Military Part Numbers	
*В	213375	See ECN	FSG	Added note to title page: "Use Ultra37000 For All New Designs"	
*C	2675372	Se <mark>e E</mark> CN	AMV	Sunset Review: Obsolete product	